Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	("6307807").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 16:54
L2	2	"20050122779"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:08
L3	2	("6411548").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:14
L4	2	("6960794").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	.2006/01/07 17:36
L5	10	(memory adj planes) and (mono$1crystalline or mono$1silicon) and (poly$1crystalline or poly$1silicon) and (glass or insulating or oxide) and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:52
L6	6	5 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:54
L7	1043	(memory adj planes)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:51
L8	13520	(mono$1crystalline or mono$1silicon) near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:51
L9	42589	(poly$1crystalline or poly$1silicon) near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:52

L10	403732	(glass or insulating or oxide) near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:52
L11	2	7 and 8 and 9 and 10 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:53
L12	4	7 and 8 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:53
L13	2683	NAND adj2 (memory or string$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:21
L14	3	7 and 13 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:02
L15	2	("6005270").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:59
L16	2	("6163048").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 17:59
L17	78602	NAND	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:02
L18	110	7 and 17 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:21
L19	11	(NAND adj2 (memory or string$1)) and (memory adj layer$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:24

L20	5	19 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:29
L21	522	NAND near10 memory near10 layer$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:24
L22	395	21 and @ad<"20031205"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 18:30